

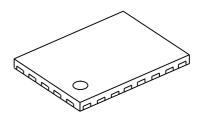
SP10T ANTENNA SWITCH GaAs MMIC

■ GENERAL DESCRIPTION

NJG1686MHH is a GaAs SP10T antenna switch MMIC suitable for LTE/3G/GSM multimode applications. This switch includes on-chip decoder circuits and low pass filters for GSM transmit port. This switch has six transmit/receive ports that provide more efficient band selection for multimode cellular application.

NJG1686MHH offers low insertion loss, high isolation, low harmonics and high linearity. The integrated ESD protection circuits in the switch IC bring excellent ESD performances. In addition, no DC blocking capacitors are required for the RF ports unless DC is biased externally. The small and thin package is adopted.

■ PACKAGE OUTLINE



NJG1686MHH

■ APPLICATIONS

Multi-mode LTE, UMTS, CDMA and GSM applications Mobile phone, Tablet PC, Data card, Modem, Router and others mobile device applications

■ FEATURES

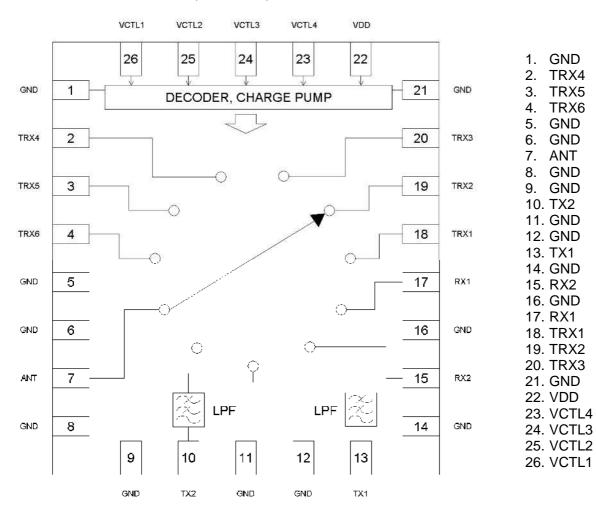
Low voltage operation	V _{DD} =+2.5V min.
Low voltage logic control	V _{CTL(H)} =+1.8V typ.
Low insertion loss	0.65dB typ. @ 452 to 960MHz, TRX1 to 3,5,6-ANT
	0.30dB typ. @ 452 to 960MHz, TRX4-ANT
	0.75dB typ. @ 1710 to 2170MHz, TRX1 to 3,5,6-ANT
	0.45dB typ. @ 1710 to 2170MHz, TRX4-ANT
	1.10dB typ. @ 2300 to 2690MHz, TRX1 to 3,5,6-ANT
	0.45dB typ. @ 2300 to 2690MHz, TRX4-ANT
	1.05dB typ. @ GSM850/900, TX1-ANT
	1.20dB typ. @ GSM1800/1900, TX2-ANT
 High isolation 	38dB typ. @GSM850/900, TX1-TRX1 to 3,5,6
-	34dB typ. @GSM1800/1900, TX2-TRX 1 to 3,5,6
	25dB typ. @f=452 to 2690MHz, TRX1-TRX3, TRX4-TRX6
	36dB typ. @f=1805 to 1990MHz, ANT-RX1,2,
	33dB typ. @f=452 to 2690MHz, opposed TRX ports
High linearity	2 nd harmonics=-80dBm typ. @f=786.5MHz
	IIP2=+95.5dBm min. @CDMA2000(AWS, PCS)
	IIP2=+102dBm min. @UMTS
No DC blocking capacitor unle	ess DC is biased externally

- Small package size EQFN26-HH (Package size: 2.6 x 3.4 x 0.7 mm typ.)
- RoHS compliant and Pb free, Halogen Free, MSL1

NOTE: The information in this document is subject to change without notice.

■ PIN CONFIGURATION

(TOP VIEW)



■ TRUTH TABLE

"H"=V _{CTL(H)} , "L"=V _{CTL(L)}							
On Path	VCTL1	VCTL2	VCTL3	VCTL4			
TX1-ANT	Н	Н	L	L			
TX2-ANT	Н	L	L	L			
ANT-RX1	L	Н	Н	L			
ANT-RX2	L	Н	L	L			
ANT-TRX1	L	Ц	Н	L			
ANT-TRX2	Н	L	Н	L			
ANT-TRX3	Н	Н	Н	L			
ANT-TRX4	Н	L	Н	Н			
ANT-TRX5	Н	Н	Н	Н			
ANT-TRX6	Н	L	L	Н			

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■ ABSOLUTE MAXIMUM RATINGS

	=+25°C, Z _s =2	Z _I =50Ω)			
PARAMETER	SYMBOL	CONDITIONS	Duty cycle	RATINGS	UNITS
		GSM LB TX1 port	4:8	36	dBm
RF Input Power	Pin	GSM HB TX2 port	4:8	34	dBm
	F II I	TRX ports	CW	32	dBm
		RX ports	CW	28	dBm
Supply Voltage	V_{DD}	VDD terminal		5.0	V
Control Voltage	V _{CTL}	VCTL terminal		5.0	V
Power dissipation	P _D	Four-layer FR4 PCB with through-hole (101.5mmx114.5mm), Tj=150°C		2200	mW
Operating Temperature	T _{opr}	-40 to +90			°C
Storage Temperature	T _{stg}			-65 to +150	°C

■ ELECTRICAL CHARACTERISTICS 1 (DC)

(General conditions: $T_a = +25^{\circ}$ C, $Z_s = Z_l = 50\Omega$, $V_{DD} = 2.7$ V, $V_{CTL(L)} = 0$ V, $V_{CTL(H)} = 1.8$ V, with application circuit)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V_{DD}		2.5	2.7	5.0	V
Operating Current	I _{DD}		-	0.40	0.65	mA
Control Current	I _{CTL}	V _{CTL(H)} =1.8V/1Port	-	4	10	μΑ
Control Voltago	V _{CTL(H)}		1.35	1.8	5.0	V
Control Voltage	V _{CTL(L)}		0	-	0.45	V

■ ELECTRICAL CHARACTERISTICS 2 (RF) (General conditions: $T_a=+25^{\circ}C$, $Z_s=Z_I=50\Omega$, $V_{DD}=2.7V$, $V_{CTL(L)}=0V$, $V_{CTL(H)}=1.8V$, with application circuit)

(General conditions	: T _a =+25°C, Z _s =Z _l =	=50Ω, V _{DD} =2.7V, V _{CTL(L)} =0V, V _{CTL(H)} =1.8V, w	/ith appl	ication of	circuit)	
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Insertion Loss 1 (1) TRX1	LOSS1(1)TRX1	TRX1 - ANT, 452 to 960MHz, Pin=26dBm	•	0.65	0.8	dB
Insertion Loss 1 (1) TRX2	LOSS1(1)TRX2	TRX2 - ANT, 452 to 960MHz, Pin=26dBm	-	0.65	0.8	dB
Insertion Loss 1 (1) TRX3	LOSS1(1)TRX3	TRX3 - ANT, 452 to 960MHz, Pin=26dBm	-	0.65	0.8	dB
Insertion Loss 1 (1) TRX4	LOSS1(1)TRX4	TRX4 - ANT, 452 to 960MHz, Pin=26dBm	-	0.3	0.45	dB
Insertion Loss 1 (1) TRX5	LOSS1(1)TRX5	TRX5 - ANT, 452 to 960MHz, Pin=26dBm	-	0.65	0.8	dB
Insertion Loss 1 (1) TRX6	LOSS1(1)TRX6	TRX6 - ANT, 452 to 960MHz, Pin=26dBm	-	0.65	0.8	dB
Insertion Loss 1 (2) TRX1	LOSS1(2)TRX1	TRX1 - ANT, 1710 to 2170MHz, Pin=26dBm	-	0.75	0.95	dB
Insertion Loss 1 (2) TRX2	LOSS1(2)TRX2	TRX2 - ANT, 1710 to 2170MHz, Pin=26dBm	-	0.9	1.1	dB
Insertion Loss 1 (2) TRX3	LOSS1(2)TRX3	TRX3 - ANT, 1710 to 2170MHz, Pin=26dBm	-	0.85	1.05	dB
Insertion Loss 1 (2) TRX4	LOSS1(2)TRX4	TRX4 - ANT, 1710 to 2170MHz, Pin=26dBm	-	0.45	0.65	dB
Insertion Loss 1 (2) TRX5	LOSS1(2)TRX5	TRX5 - ANT, 1710 to 2170MHz, Pin=26dBm	-	0.85	1.05	dB
Insertion Loss 1 (2) TRX6	LOSS1(2)TRX6	TRX6 - ANT, 1710 to 2170MHz, Pin=26dBm	-	0.75	0.95	dB
Insertion Loss 1 (3) TRX1	LOSS1(3)TRX1	TRX1 - ANT, 2300 to 2690MHz, Pin=26dBm	-	1.1	1.4	dB
Insertion Loss 1 (3) TRX2	LOSS1(3)TRX2	TRX2 - ANT, 2300 to 2690MHz, Pin=26dBm	-	1.25	1.55	dB
Insertion Loss 1 (3) TRX3	LOSS1(3)TRX3	TRX3 - ANT, 2300 to 2690MHz, Pin=26dBm	-	1.15	1.45	dB
Insertion Loss 1 (3) TRX4	LOSS1(3)TRX4	TRX4 - ANT, 2300 to 2690MHz, Pin=26dBm	-	0.45	0.75	dB
Insertion Loss 1 (3) TRX5	LOSS1(3)TRX5	TRX5 - ANT, 2300 to 2690MHz, Pin=26dBm	-	1.1	1.4	dB
Insertion Loss 1 (3) TRX6	LOSS1(3)TRX6	TRX6 - ANT, 2300 to 2690MHz, Pin=26dBm	-	1.1	1.4	dB
Insertion Loss 2	LOSS2	TRX4 – ANT, 704 to 787MHz (Band13, Band17), Pin=26dBm	-	0.25	0.4	dB
Insertion Loss 3	LOSS3	TX1 – ANT, 824 to 915MHz, Pin=35dBm	-	1.05	1.3	dB
Insertion Loss 4	LOSS4	TX2 – ANT, 1710 to 1910MHz, Pin=32dBm	-	1.2	1.4	dB
Insertion Loss 5(1)	LOSS5(1)	RX1,2 – ANT, 869 to 960MHz, Pin=10dBm	-	0.9	1.1	dB
Insertion Loss 5(2)	LOSS5(2)	RX1,2 – ANT, 1805 to 1990MHz, Pin=10dBm	-	1.0	1.2	dB

■ ELECTRICAL CHARACTERISTICS 3 (RF) (General conditions: T_a=+25°C, Z_s=Z_I=50Ω, V_{DD}=2.7V, V_{CTL(L)}=0V, V_{CTL(H)}=1.8V, with application circuit)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Isolation 1(1)	ISL1(1)	TX1-TRX1 to 3,TRX5,6,RX1 (TX1 ON) f=824 to 915MHz	35	38	-	dB
Isolation 1(2)	ISL1(2)	TX1-TRX4,RX2 (TX1 ON) f=824 to 915MHz	33	35	-	dB
Isolation 2(1)	ISL2(1)	TX2-TRX1 to 3, TRX5,6, RX1,2 (TX2 ON) f=1710 to 1910MHz	32	35	-	dB
Isolation 2(2)	ISL2(2)	TX2-TRX4 (TX2 ON) f=1710 to 1910MHz	31	34	-	dB
Isolation 3	ISL3	TRX1 – TRX3, TRX4 – TRX6, 452 to 2690MHz	23	25	-	dB
Isolation 4	ISL4	TRX1 – TRX2, TRX2 – TRX3, TRX4 – TRX5, TRX5 – TRX6, 452 to 2690MHz	17	20	-	dB
Isolation 5	ISL5	ANT – RX1 (RX2 ON), ANT – RX2 (RX1 ON), 1805 to 1990MHz	33	36	-	dB
Isolation 6(1)	ISL6(1)	TRX1 to 3 – TRX4 to 6 (TRX1 to 3 ON), 452 to 2690MHz	25	27	-	dB
Isolation 6(2)	ISL6(2)	TRX1 to 3 – TRX4 to 6 (TRX4 to 6 ON), 452 to 2690MHz	31	33	-	dB
VSWR (1)	VSWR (1)	TX1 ON 824 to 915MHz	-	-	1.5	-
VSWR (2)	VSWR (2)	TX2 ON 1710 to 1910MHz	-	-	1.6	-
VSWR (3)	VSWR (3)	TRX1 to 6 452 to 2170MHz	-	-	1.6	-
VSWR (4)	VSWR (4)	TRX1 to 6 452 to 2690MHz	-	-	1.8	-
VSWR (5)	VSWR (5)	RX1 to 2 869 to 1990MHz	-	-	1.5	-
Switching Speed	TSW	50% V _{CTL(H)} to 10/90% RF	-	3	5	μS

■ ELECTRICAL CHARACTERISTICS 4 (RF) (General conditions: T_a=+25°C, Z_s=Z_I=50Ω, V_{DD}=2.7V, V_{CTL(L)}=0V, V_{CTL(H)}=1.8V, with application circuit)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Triple Beat Ratio	TBR	TRX1 to 6 ON, 650 to 900 MHz 1710 to 2155 MHz	-	80	-	dBc
2nd Harmonics 1	2fo(1)	TRX1 to 6 ON, 452 to 1980 MHz, Pin=26dBm	-	-	-62	dBc
2nd Harmonics 2	2fo(2)	TX1 ON, 824 to 915 MHz Pin=35dBm	-	-	-70	dBc
2nd Harmonics 3	2fo(3)	TX2 ON, 1710 to 1910 MHz Pin=32dBm	-	-	-67	dBc
2nd Harmonics 4	2fo(4)	TRX4 ON, 786.5MHz (Band13), Pin=25dBm	-	-80	-	dBm
3rd Harmonics 1	3fo(1)	TRX1 to 6 ON, 452 to 1980 MHz, Pin=26dBm	-	-	-62	dBc
3rd Harmonics 2	3fo(2)	TX1 ON, 824 to 915 MHz Pin=35dBm	-	-	-70	dBc
3rd Harmonics 3	3fo(3)	TX2 ON, 1710 to 1910 MHz Pin=32dBm	-	-	-67	dBc
GSM Tx Attenuation 1	ATT(1)	TX1 ON, 2fo, 3fo	25	-	-	dB
GSM Tx Attenuation 2	ATT(2)	TX1 ON, Past 3fo to 12.75 GHz	16	-	-	dB
GSM Tx Attenuation 3	ATT(3)	TX2 ON, 2fo, 3fo	25	-	-	dB
GSM Tx Attenuation 4	ATT(4)	TX2 ON, Past 6.84 to 12.75 GHz	14	-	-	dB

■ ELECTRICAL CHARACTERISTICS 5 (RF)

PARAMETER	SYMBOL	$\frac{1=50\Omega}{CONDITIONS}$	MIN	TYP	MAX	UNITS
IIP3(1) – UMTS mode (2600)	IIP3(1)	*Table 1, TRX1 to 6 ON	+60	-	-	dBm
IIP3(2) – UMTS mode (IMT)	IIP3(2)	*Table 1, TRX1 to 6 ON	+60	-	-	dBm
IIP3(3) – UMTS mode (PCS)	IIP3(3)	*Table 1, TRX1 to 6 ON	+61	-	-	dBm
IIP3(4) _ UMTS mode (DCS)	IIP3(4)	*Table 1, TRX1 to 6 ON	+61	-	-	dBm
IIP3(5) <u> </u>	IIP3(5)	*Table 1, TRX1 to 6 ON	+61	-	-	dBm
IIP3(6) UMTS mode (900)	IIP3(6)	*Table 1, TRX1 to 6 ON	+61	-	-	dBm
IIP3(7) <u> </u>	IIP3(7)	*Table 1, TRX1 to 6 ON	+61	-	-	dBm
IIP2(1) UMTS mode (2600)	IIP2(1)	*Table 1, TRX1 to 6 ON	+102	-	-	dBm
IIP2(2) UMTS mode (IMT)	IIP2(2)	*Table 1, TRX1 to 6 ON	+102	-	-	dBm
IIP2(3) <u> </u>	IIP2(3)	*Table 1, TRX1 to 6 ON	+102	-	-	dBm
IIP2(4) <u> </u>	IIP2(4)	*Table 1, TRX1 to 6 ON	+102	-	-	dBm
IIP2(5) _ UMTS mode (PDC)	IIP2(5)	*Table 1, TRX1 to 6 ON	+102	-	-	dBm
IIP2(6) UMTS mode (900)	IIP2(6)	*Table 1, TRX1 to 6 ON	+102	-	-	dBm
IIP2(7) UMTS mode (US cell)	IIP2(7)	*Table 1, TRX1 to 6 ON	+102	-	-	dBm
IIP2(8) C2K mode (AWS)	IIP2(8)	*Table 2, TRX1 to 6 ON	+95.5	-	-	dBm
IIP2(9) – C2K mode (PCS)	IIP2(9)	*Table 2, TRX1 to 6 ON	+95.5	-	-	dBm
IIP2(10) – C2K mode (cell)	IIP2(10)	*Table 2, TRX1 to 6 ON	+111.5	-	-	dBm

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	Band	CW tone 1	CW tone 1	CW tone 2	CW tone 2	Min IIP 2
	Dana					
		(MHz)	(dBm)	(MHz)	(dBm)	(dBm)
	2600	2535	20	120	-15	+102
	IMT	1950	20	190	-15	+102
	PCS	1880	20	80	-15	+102
IIP2	DCS	1745	20	95	-15	+102
	PDC	1440	20	48	-15	+102
	900	892	20	45	-15	+102
	US cell	835	20	45	-15	+102
	2600	2535	20	2415	-15	+60
	IMT	1950	20	1760	-15	+60
	PCS	1880	20	1800	-15	+61
IIP3	DCS	1745	20	1650	-15	+61
	PDC	1440	20	1392	-15	+61
	900	892	20	847	-15	+61
	US cell	835	20	790	-15	+61

Table 1 IIP2/IIP3 UMTS Mode

Table 2 IIP2 C2k Mode

Band	Temp	In-band	CW tone 1	CW tone	CW tone 2	CW tone 2	Min IIP 2
	(°C)	Freq (MHz)	Freq (MHz)	Power (dBm)	Freq (MHz)	Power (dBm)	(dBm)
	25	869.28	824.28	26	1693.56	-20	+111.5
Cell	-30, 25, 85	881.61	836.61	26	1718.22	-20	+111.5
	25	893.31	848.31	26	1741.62	-20	+111.5
	25	1930.05	1850.05	26	3780.1	-20	+95.5
PCS	-30, 25, 85	1965	1885	26	3850	-20	+95.5
	25	1989.95	1909.95	26	3899.9	-20	+95.5
	25	2110	1710	26	3820	-20	+95.5
AWS	-30, 25, 85	2132.5	1732.5	26	3865	-20	+95.5
	25	2155	1755	26	3910	-20	+95.5

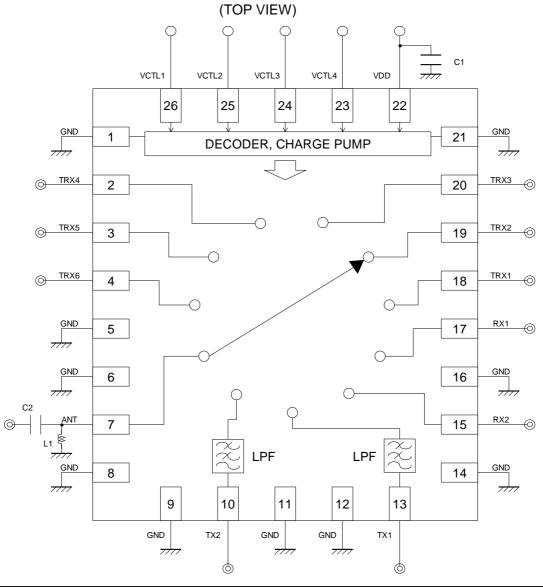
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TERMINAL INFORMATION

No.	SYMBOL	DESCRIPTION
1	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
2	TRX4	RF transmitting/receiving port.
3	TRX5	RF transmitting/receiving port.
4	TRX6	RF transmitting/receiving port.
5	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
6	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
7	ANT	RF transmitting/receiving port. Please connect an inductor and capacitor with GND terminal for enhancing ESD protection, keeping zero DC Voltage at RF ports, and good RF characteristics.
8	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
9	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
10	TX2	RF transmitting port. This port is connected the LPF for GSM1800/1900 TX band.
11	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
12	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
13	TX1	RF transmitting port. This port is connected the LPF for GSM850/900 TX Band.
14	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
15	RX2	RF receiving port.
16	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
17	RX1	RF receiving port.
18	TRX1	RF transmitting/receiving port.
19	TRX2	RF transmitting/receiving port.
20	TRX3	RF transmitting/receiving port.
21	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
22	VDD	Positive voltage supply terminal. The positive voltage (+2.5 to +5.0V) has to be supplied. Please connect a bypass capacitor with GND terminal for excellent RF performance.
23	VCTL4	Control signal input terminal. This terminal is set to High-Level (+1.35 to +5.0V) or Low-Level (0 to +0.45V).
24	VCTL3	Control signal input terminal. This terminal is set to High-Level (+1.35 to +5.0V) or Low-Level (0 to +0.45V).
25	VCTL2	Control signal input terminal. This terminal is set to High-Level (+1.35 to +5.0V) or Low-Level (0 to +0.45V).
26	VCTL1	Control signal input terminal. This terminal is set to High-Level (+1.35 to +5.0V) or Low-Level (0 to +0.45V).

NJG1686MHH

■ APPLICATION CIRCUIT



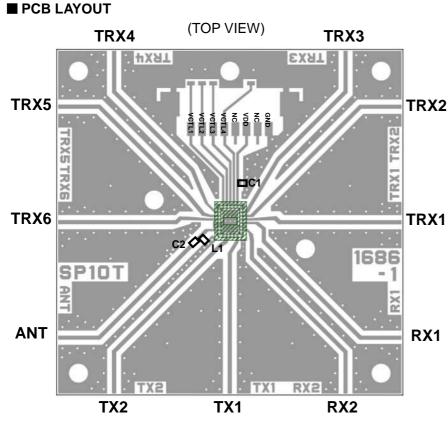
No DC blocking capacitors are required on all RF ports, unless DC is biased externally.

■ PARTS LIST

No.	Parameters	Note
C1	1000 pF	MURATA (GRM15)
C2 *1	47pF	MURATA (GRM15)
L1 ^{*1}	56 nH	TDK (MLG1005S)

*1: The use of the inductor L1 and the capacitor C2 are needed in order to keep zero DC Voltage at RF ports, enhancing ESD protection level, and for good RF characteristics.

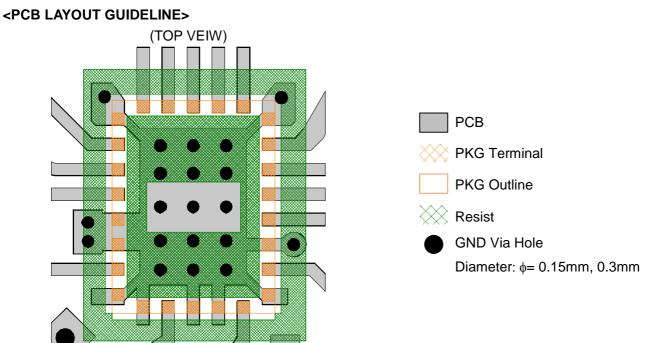
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Losses of PCB and connectors, Ta=+25°C

2	Frequency (MHz)	ANT-TX2, RX1,2, TRX2,3,4,5 Loss (dB)	ANT-TX1, TRX1,6 Loss (dB)	
	787	0.36	0.34	
	915	0.38	0.35	
	960	0.37	0.34	
	1910	0.58	0.53	
	2170	0.64	0.57	
	2690	0.72	0.66	

PCB SIZE: 38.9 x 38.9 mm PCB: FR-4, t=0.2mm MICROSTRIP LINE WIDTH: 0.4mm Areas being hatched are covered with resist.



■ PRECAUTIONS

- [1] No DC block capacitors are required for RF ports unless DC is biased externally.
- [2] For avoiding the degradation of RF performance, the bypass capacitor (C1) should be placed as close as possible to VDD terminal
- [3] For good RF performance, all GND terminals are must be connected to PCB ground plane of substrate, and through holes for GND should be placed the IC near.

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■ RECOMMENDED FOOTPRINT PATTERN (EQFN26-HH PACKAGE REFERENCE)

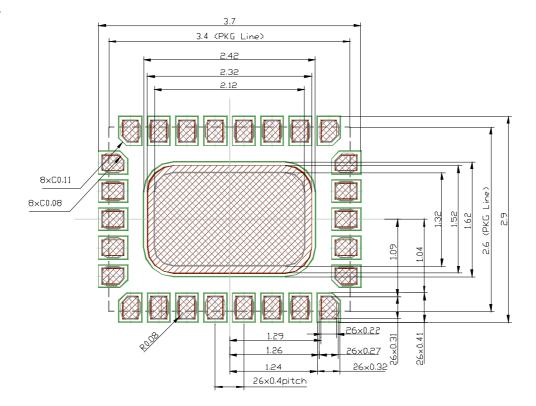
🌌 : Land

: Mask (Open area) *Metal mask thickness : 100 μ m

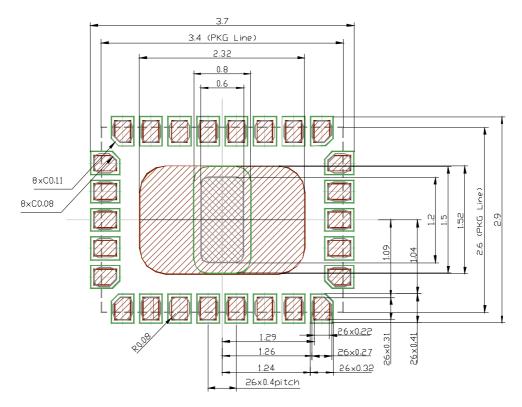
PKG : 3.4mm x 2.6mm Pin pitch : 0.4mm

: Resist (Open area)

<TYPE 1> *



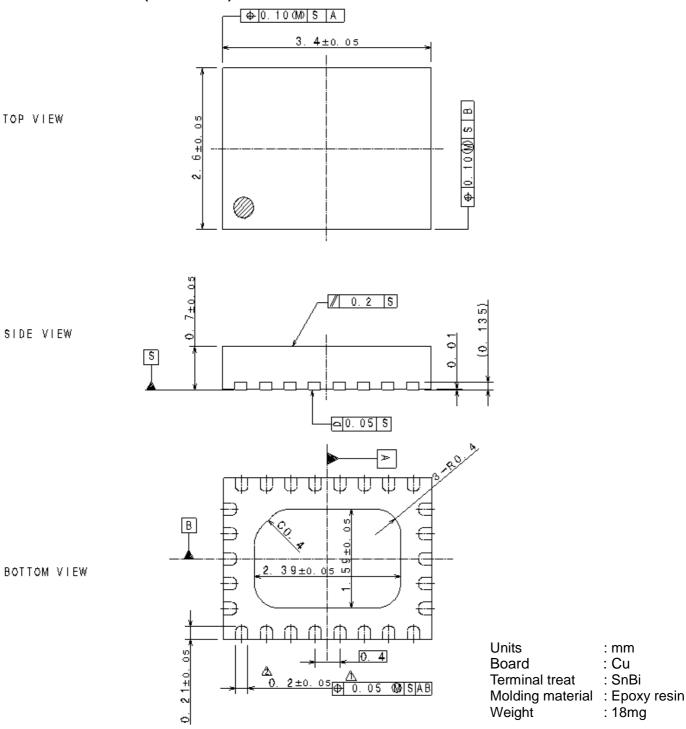
< TYPE 2> *



* There is no difference in the characteristics using both of TYPE 1 and TYPE 2.

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■ PACKAGE OUTLINE (EQFN26-HH)



Cautions on using this product

- This product contains Gallium-Arsenide (GaAs) which is a harmful material.
- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

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[CAUTION]

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 - Traffic control system
 - Combustion equipment

In case your company desires to use this product for any applications other than general electronic equipment mentioned above, make sure to contact our company in advance. Note that the important requirements mentioned in this section are not applicable to cases where operation requirements such as application conditions are confirmed by our company in writing after consultation with your company.

- 6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
- 7. The products have been designed and tested to function within controlled environmental conditions. Do not use products under conditions that deviate from methods or applications specified in this datasheet. Failure to employ the products in the proper applications can lead to deterioration, destruction or failure of the products. We shall not be responsible for any bodily injury, fires or accident, property damage or any consequential damages resulting from misuse or misapplication of the products.
- 8. Quality Warranty
 - 8-1. Quality Warranty Period

In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.

8-2. Quality Warranty Remedies

When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.

- Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
- 8-3. Remedies after Quality Warranty Period

With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.

- 9. Anti-radiation design is not implemented in the products described in this document.
- 10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
- 12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
- 13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



Nisshinbo Micro Devices Inc.

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